

# UNISONIC TECHNOLOGIES CO., LTD

MN2510

**Preliminary** 

NPN EPITAXIAL SILICON TRANSISTOR

# NPN TRANSISTOR

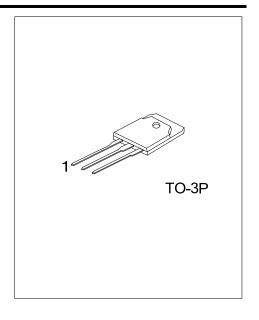
#### DESCRIPTION

The UTC MN2510 is an NPN transistor, it uses UTC's advanced technology to provide the customers with high DC current gain and high collector-emitter breakdown voltage, etc.

The UTC MN2510 is suitable for automobile power amplifiers, etc.

#### **FEATURES**

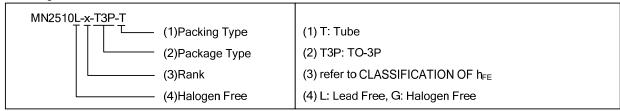
- \* High DC current gain (MIN =  $40 @V_{CE} = 4V$ ,  $I_C = 12A$ )
- \* High collector-emitter breakdown voltage (MIN = 100V)



### ORDERING INFORMATION

Ordering Number		Dardina	Pin Assignment			Doolsing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MN2510L-x-T3P-T	MN2510G-x-T3P-T	TO-3P	В	С	Е	Tube	

E: Emitter Pin Assignment: B: Base C: Collector



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## ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	$V_{CBO}$	100	V
Collector-Emitter Voltage	$V_{\sf CEO}$	100	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current	Ic	25	А
Base Current	I <sub>B</sub>	5	А
Collector Power Dissipation (T <sub>C</sub> =25°C)	Pc	125	W
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

## ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-Off Current	I <sub>CBO</sub>	V <sub>CB</sub> =100V			10	μA
Emitter Cut-Off Current	I <sub>EBO</sub>	V <sub>EB</sub> =6V			10	μΑ
Collector-Emitter Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =50mA	100			V
DC Current Gain (Note 1)	h <sub>FE</sub>	$V_{CE}=4V$ , $I_{C}=12A$	40		120	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =12A, I <sub>B</sub> =1.2A			1.5	V
Base- Emitter Saturation Voltage	$V_{BE(ON)}$	$V_{CE}=4V$ , $I_{C}=12A$			1.8	V
Cut-Off Frequency	$f_{T}$	V <sub>CE</sub> =12V, I <sub>E</sub> =-1A		20		MHz
Output Capacitance	$C_ob$	$V_{CB}=10V$ , $I_{E}=0A$ , $f=1MHz$		200		pF

## ■ CLASSIFICATION OF h<sub>FE</sub>

RANK	R	0
h <sub>FF1</sub>	40~80	60~120



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